

5. (Amended) A light-emitting device according to Claim 3, wherein said second layer comprises a metal compound having said metal and a material selected from the group consisting of oxides, nitrides and oxide-nitrides.

8. (Amended) A light-emitting device according to Claim 1, wherein said device comprises, on a transparent substrate, a built-up body including said anode, an organic layer containing said emission region and said cathode.

13. (New) A light-emitting device according to Claim 1, where said anode has a dopant selected from the group consisting of H, Li, Na, K, Rb, Cs, Cu, Ag, and Au.

14. (New) A light-emitting device according to Claim 1, where said anode has a dopant material selected from the group consisting of  $R_xNiO$ ,  $R_xWO_3$ , and  $TiNb_xO_y$ , wherein R is selected from the group consisting of H, Li, Na, K, Rb, Cs, Cu, Ag, and Au.

, said second layer having a thickness having a thickness such that said light-emitting device an luminance and a contrast of said light-emitting device.

15. (New) A light-emitting device according to Claim 3, where said second layer has a thickness in the range of 15 nm to 80 nm.

16. (New) A light-emitting device according to Claim 15, where said light-emitting device has a luminance that increases within the range of 620 to 1200 cd m<sup>2</sup> as said thickness of said second layer is decreased within the range of 15 nm to 80 nm and has a contrast corresponding to said luminance that increases within the range of 250:1 to 410:1 as said thickness of said second layer is decreased within the range of 15 nm to 80 nm.

17. (New) A light-emitting device comprising an inorganic layer including an emission region and provided between an anode and a cathode wherein said anode has a visible light transmittance of 35 to 75%.

18. (New) A light-emitting device according to Claim 17, wherein the visible light has a wavelength ranging from 380 nm to 780 nm.

19. (New) A light-emitting device according to Claim 17, wherein said anode comprises a metal selected from the group consisting of Ni, Ru, Ir, Rh, Pt, Pd, Re, Ti, Zr, Nb, Mo, and W.

20. (New) A light-emitting device according to Claim 19, wherein said anode comprises a metal compound having said metal and a material selected from the group consisting of oxides, nitrides and oxide-nitrides.

21. (New) A light-emitting device according to Claim 19, wherein said anode comprises a plurality of layers, a first of the layers having a material selected from the group consisting of zinc, indium or tin, a second of the layers having said metal.

22. (New) A light-emitting device according to Claim 19, wherein said anode has a dopant selected from the group consisting of H, Li, Na, K, Rb, Cs, Cu, Ag, and Au.

23. (New) A light-emitting device according to Claim 17, wherein said anode has a work function of 3.0 to 7.0 eV.

#### REMARKS

Claims 1-12 are pending in the above-identified application. Claims 1-12 were rejected. With this Amendment, claims 1, 3, 5, and 8 were amended, claims 4 and 6 are canceled and